

# RF Power LDMOS Transistors

## High Ruggedness N-Channel Enhancement-Mode Lateral MOSFETs

These high ruggedness devices are designed for use in high VSWR defense and commercial radio communications and HF, VHF and UHF radar applications. The unmatched input and output designs allow wide frequency range utilization, from 1.8 to 600 MHz.

**Typical Performance:**  $V_{DD} = 50 \text{ Vdc}$

| Frequency (MHz) | Signal Type                                     | P <sub>out</sub> (W) | G <sub>ps</sub> (dB) | $\eta_D$ (%) |
|-----------------|-------------------------------------------------|----------------------|----------------------|--------------|
| 230             | CW                                              | 150                  | 26.3                 | 72.0         |
| 230             | Pulse<br>(100 $\mu\text{sec}$ , 20% Duty Cycle) | 150 Peak             | 26.1                 | 70.3         |

### Load Mismatch/Ruggedness

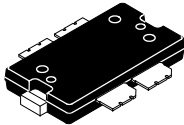
| Frequency (MHz) | Signal Type                                     | VSWR                       | P <sub>in</sub> (W)           | Test Voltage | Result                |
|-----------------|-------------------------------------------------|----------------------------|-------------------------------|--------------|-----------------------|
| 230             | Pulse<br>(100 $\mu\text{sec}$ , 20% Duty Cycle) | > 65:1 at all Phase Angles | 0.62 Peak<br>(3 dB Overdrive) | 50           | No Device Degradation |

### Features

- Wide operating frequency range
- Extreme ruggedness
- Unmatched input and output allowing wide frequency range utilization
- Integrated stability enhancements
- Low thermal resistance
- Integrated ESD protection circuitry

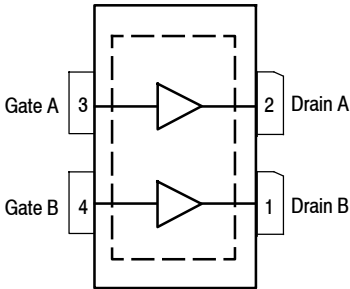
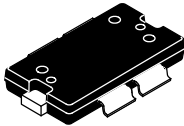
**MMRF1320N**  
**MMRF1320GN**

**1.8–600 MHz, 150 W CW, 50 V**  
**WIDEBAND**  
**RF POWER LDMOS TRANSISTORS**



**TO-270WB-4  
PLASTIC  
MMRF1320N**

**TO-270WBG-4  
PLASTIC  
MMRF1320GN**



(Top View)

Note: Exposed backside of the package is the source terminal for the transistors.

**Figure 1. Pin Connections**

**Table 1. Maximum Ratings**

| Rating                                                                     | Symbol    | Value       | Unit      |
|----------------------------------------------------------------------------|-----------|-------------|-----------|
| Drain–Source Voltage                                                       | $V_{DS}$  | –0.5, +133  | Vdc       |
| Gate–Source Voltage                                                        | $V_{GS}$  | –6.0, +10   | Vdc       |
| Storage Temperature Range                                                  | $T_{stg}$ | –65 to +150 | °C        |
| Case Operating Temperature Range                                           | $T_C$     | –40 to +150 | °C        |
| Operating Junction Temperature Range <sup>(1,2)</sup>                      | $T_J$     | –40 to +225 | °C        |
| Total Device Dissipation @ $T_C = 25^{\circ}\text{C}$<br>Derate above 25°C | $P_D$     | 952<br>4.76 | W<br>W/°C |

**Table 2. Thermal Characteristics**

| Characteristic                                                                                                                                                                       | Symbol          | Value <sup>(2,3)</sup> | Unit |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------|------------------------|------|
| Thermal Resistance, Junction to Case<br>CW: Case Temperature 80°C, 150 W CW, 50 Vdc, $I_{DQ(A+B)} = 100\text{ mA}$ , 230 MHz                                                         | $R_{\theta JC}$ | 0.21                   | °C/W |
| Thermal Impedance, Junction to Case<br>Pulse: Case Temperature 66°C, 150 W Peak, 100 $\mu\text{sec}$ Pulse Width,<br>20% Duty Cycle, 50 Vdc, $I_{DQ(A+B)} = 100\text{ mA}$ , 230 MHz | $Z_{\theta JC}$ | 0.04                   | °C/W |

**Table 3. ESD Protection Characteristics**

| Test Methodology                      | Class             |
|---------------------------------------|-------------------|
| Human Body Model (per JESD22-A114)    | 2, passes 2500 V  |
| Machine Model (per EIA/JESD22-A115)   | B, passes 250 V   |
| Charge Device Model (per JESD22-C101) | IV, passes 1200 V |

**Table 4. Moisture Sensitivity Level**

| Test Methodology                     | Rating | Package Peak Temperature | Unit |
|--------------------------------------|--------|--------------------------|------|
| Per JESD22-A113, IPC/JEDEC J-STD-020 | 3      | 260                      | °C   |

**Table 5. Electrical Characteristics** ( $T_A = 25^{\circ}\text{C}$  unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

**Off Characteristics <sup>(4)</sup>**

|                                                                                                    |               |     |     |    |                 |
|----------------------------------------------------------------------------------------------------|---------------|-----|-----|----|-----------------|
| Gate–Source Leakage Current<br>( $V_{GS} = 5\text{ Vdc}$ , $V_{DS} = 0\text{ Vdc}$ )               | $I_{GSS}$     | —   | —   | 1  | $\mu\text{Adc}$ |
| Drain–Source Breakdown Voltage<br>( $V_{GS} = 0\text{ Vdc}$ , $I_D = 50\text{ mAdc}$ )             | $V_{(BR)DSS}$ | 133 | 139 | —  | Vdc             |
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 50\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ )  | $I_{DSS}$     | —   | —   | 5  | $\mu\text{Adc}$ |
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 100\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ ) | $I_{DSS}$     | —   | —   | 10 | $\mu\text{Adc}$ |

**On Characteristics**

|                                                                                                               |              |     |      |     |     |
|---------------------------------------------------------------------------------------------------------------|--------------|-----|------|-----|-----|
| Gate Threshold Voltage <sup>(4)</sup><br>( $V_{DS} = 10\text{ Vdc}$ , $I_D = 480\text{ }\mu\text{Adc}$ )      | $V_{GS(th)}$ | 1.8 | 2.4  | 2.8 | Vdc |
| Gate Quiescent Voltage<br>( $V_{DD} = 50\text{ Vdc}$ , $I_D = 100\text{ mAdc}$ , Measured in Functional Test) | $V_{GS(Q)}$  | 2.3 | 2.8  | 3.3 | Vdc |
| Drain–Source On–Voltage <sup>(4)</sup><br>( $V_{GS} = 10\text{ Vdc}$ , $I_D = 1\text{ Adc}$ )                 | $V_{DS(on)}$ | —   | 0.26 | —   | Vdc |

1. Continuous use at maximum temperature will affect MTTF.
2. MTTF calculator available at <http://www.freescale.com/rf/calculators>.
3. Refer to [AN1955](#), *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.freescale.com/rf> and search for AN1955.
4. Each side of device measured separately.

(continued)

**Table 5. Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (continued)

| Characteristic                                                                                                        | Symbol    | Min | Typ  | Max | Unit |
|-----------------------------------------------------------------------------------------------------------------------|-----------|-----|------|-----|------|
| <b>Dynamic Characteristics</b> <sup>(1)</sup>                                                                         |           |     |      |     |      |
| Reverse Transfer Capacitance<br>( $V_{DS} = 50\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz, $V_{GS} = 0\text{ Vdc}$ ) | $C_{rss}$ | —   | 0.8  | —   | pF   |
| Output Capacitance<br>( $V_{DS} = 50\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz, $V_{GS} = 0\text{ Vdc}$ )           | $C_{oss}$ | —   | 45.4 | —   | pF   |
| Input Capacitance<br>( $V_{DS} = 50\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz)            | $C_{iss}$ | —   | 96.7 | —   | pF   |

**Functional Tests** <sup>(2)</sup> (In Freescale Test Fixture, 50 ohm system)  $V_{DD} = 50\text{ Vdc}$ ,  $I_{DQ(A+B)} = 100\text{ mA}$ ,  $P_{out} = 150\text{ W Peak}$  (30 W Avg.),  $f = 230\text{ MHz}$ , 100  $\mu\text{sec}$  Pulse Width, 20% Duty Cycle

|                   |          |      |      |      |    |
|-------------------|----------|------|------|------|----|
| Power Gain        | $G_{ps}$ | 25.0 | 26.1 | 27.5 | dB |
| Drain Efficiency  | $\eta_D$ | 68.0 | 70.3 | —    | %  |
| Input Return Loss | IRL      | —    | −16  | −9   | dB |

**Load Mismatch/Ruggedness** (In Freescale Test Fixture) 50 ohm system,  $I_{DQ(A+B)} = 100\text{ mA}$

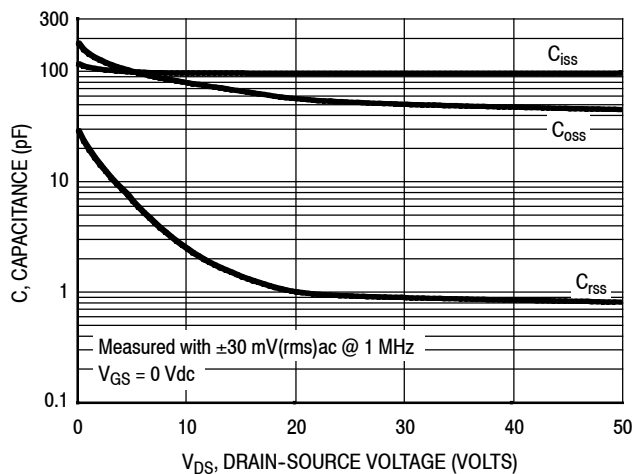
| Frequency (MHz) | Signal Type                                     | VSWR                          | $P_{in}$ (W)                  | Test Voltage, $V_{DD}$ | Result                |
|-----------------|-------------------------------------------------|-------------------------------|-------------------------------|------------------------|-----------------------|
| 230             | Pulse<br>(100 $\mu\text{sec}$ , 20% Duty Cycle) | > 65:1<br>at all Phase Angles | 0.62 Peak<br>(3 dB Overdrive) | 50                     | No Device Degradation |

**Table 6. Ordering Information**

| Device       | Tape and Reel Information                             | Package     |
|--------------|-------------------------------------------------------|-------------|
| MMRF1320NR1  | R1 Suffix = 500 Units, 44 mm Tape Width, 13-inch Reel | TO-270WB-4  |
| MMRF1320GNR1 |                                                       | TO-270WBG-4 |

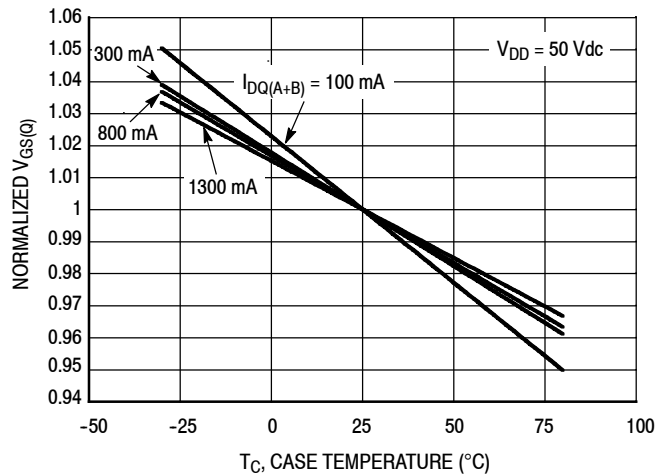
- Each side of device measured separately.
- Measurements made with device in straight lead configuration before any lead forming operation is applied. Lead forming is used for gull wing (GN) parts.

## TYPICAL CHARACTERISTICS



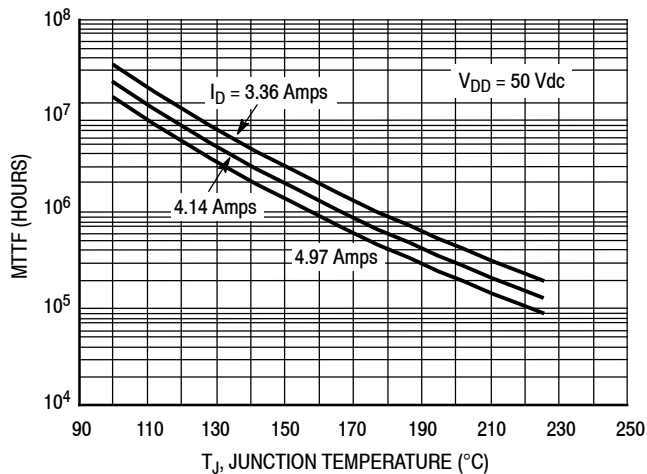
**Note:** Each side of device measured separately.

**Figure 2. Capacitance versus Drain-Source Voltage**



| $I_{DQ}$ (mA) | Slope (mV/°C) |
|---------------|---------------|
| 100           | -2.466        |
| 300           | -2.058        |
| 800           | -2.015        |
| 1300          | -1.877        |

**Figure 3. Normalized  $V_{GS}$  versus Quiescent Current and Case Temperature**



**Note:** MTTF value represents the total cumulative operating time under indicated test conditions.

MTTF calculator available at <http://www.freescale.com/rf/calculators>.

**Figure 4. MTTF versus Junction Temperature - CW**

## 230 MHz NARROWBAND PRODUCTION TEST FIXTURE

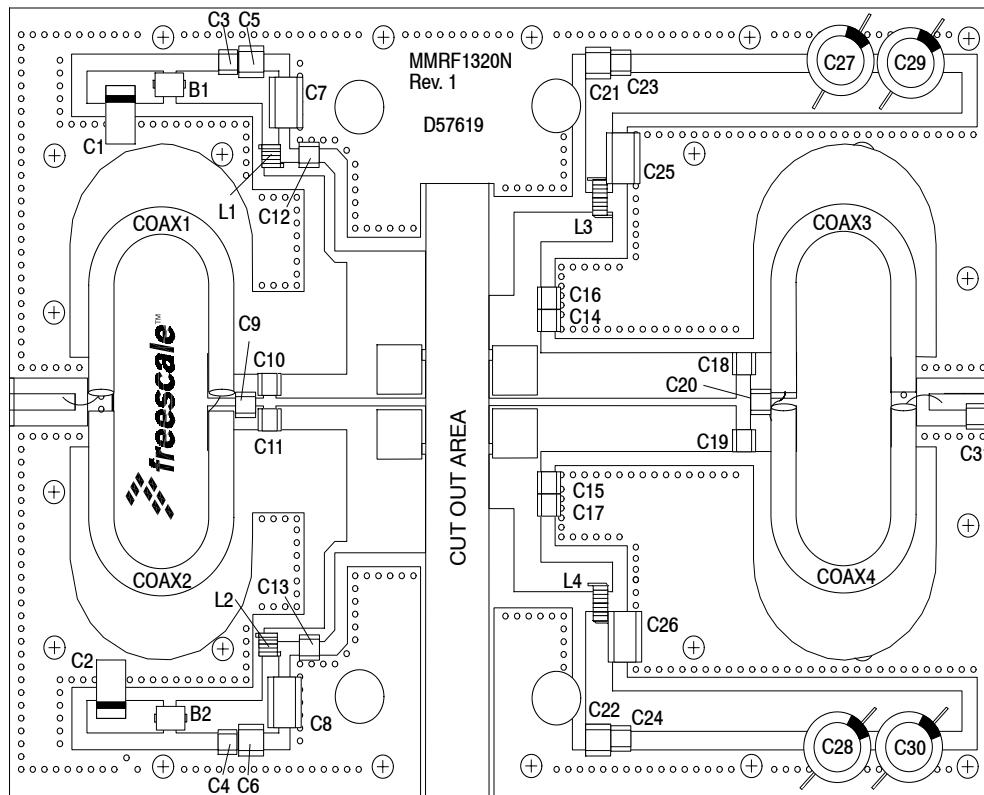


Figure 5. MMRF1320N Narrowband Test Circuit Component Layout — 230 MHz

## 230 MHz NARROWBAND PRODUCTION TEST FIXTURE

**Table 7. MMRF1320N Narrowband Test Circuit Component Designations and Values — 230 MHz**

| Part               | Description                                    | Part Number          | Manufacturer |
|--------------------|------------------------------------------------|----------------------|--------------|
| B1, B2             | Small Ferrite Beads, Surface Mount             | 2743019447           | Fair-Rite    |
| C1, C2             | 22 $\mu$ F, 35 V Tantalum Capacitors           | T491X226K035AT       | Kemet        |
| C3, C4, C23, C24   | 0.1 $\mu$ F Chip Capacitors                    | CDR33BX104AKWS       | AVX          |
| C5, C6             | 220 nF Chip Capacitors                         | C1812C224K5RACTU     | Kemet        |
| C7, C8             | 2.2 $\mu$ F Chip Capacitors                    | C1825C225J5RACTU     | Kemet        |
| C9                 | 2.2 pF Chip Capacitor                          | ATC100B2R2JT500XT    | ATC          |
| C10, C11           | 18 pF Chip Capacitors                          | ATC100B180JT500XT    | ATC          |
| C12, C13           | 330 pF Chip Capacitors                         | ATC100B331JT200XT    | ATC          |
| C14, C15           | 39 pF Chip Capacitors                          | ATC100B390JT500XT    | ATC          |
| C16, C17           | 15 pF Chip Capacitors                          | ATC100B150JT500XT    | ATC          |
| C18, C19           | 1000 pF Chip Capacitors                        | ATC100B102JT50XT     | ATC          |
| C20                | 82 pF Chip Capacitor                           | ATC100B820JT500XT    | ATC          |
| C21, C22           | 0.10 $\mu$ F Chip Capacitors                   | C1812F104K1RACTU     | Kemet        |
| C25, C26           | 2.2 $\mu$ F Chip Capacitors                    | 2225X7R225KT3AB      | ATC          |
| C27, C28, C29, C30 | 470 $\mu$ F, 63 V Electrolytic Capacitors      | MCGPR63V477M13X26-RH | Multicomp    |
| C31                | 36 pF Chip Capacitor                           | ATC100B360JT500XT    | ATC          |
| Coax1, 2, 3, 4     | 25 $\Omega$ SemiRigid Coax, 2.4" Shield Length | UT-141C-25           | Micro-Coax   |
| L1, L2             | 3 Turns, 12 nH Inductors                       | GA3094-ALC           | Coilcraft    |
| L3, L4             | 4 Turns, 17.5 nH Inductors                     | GA3095-ALC           | Coilcraft    |
| PCB                | Arlon AD255A, 0.030", $\epsilon_r = 2.55$      | D57619               | MTL          |

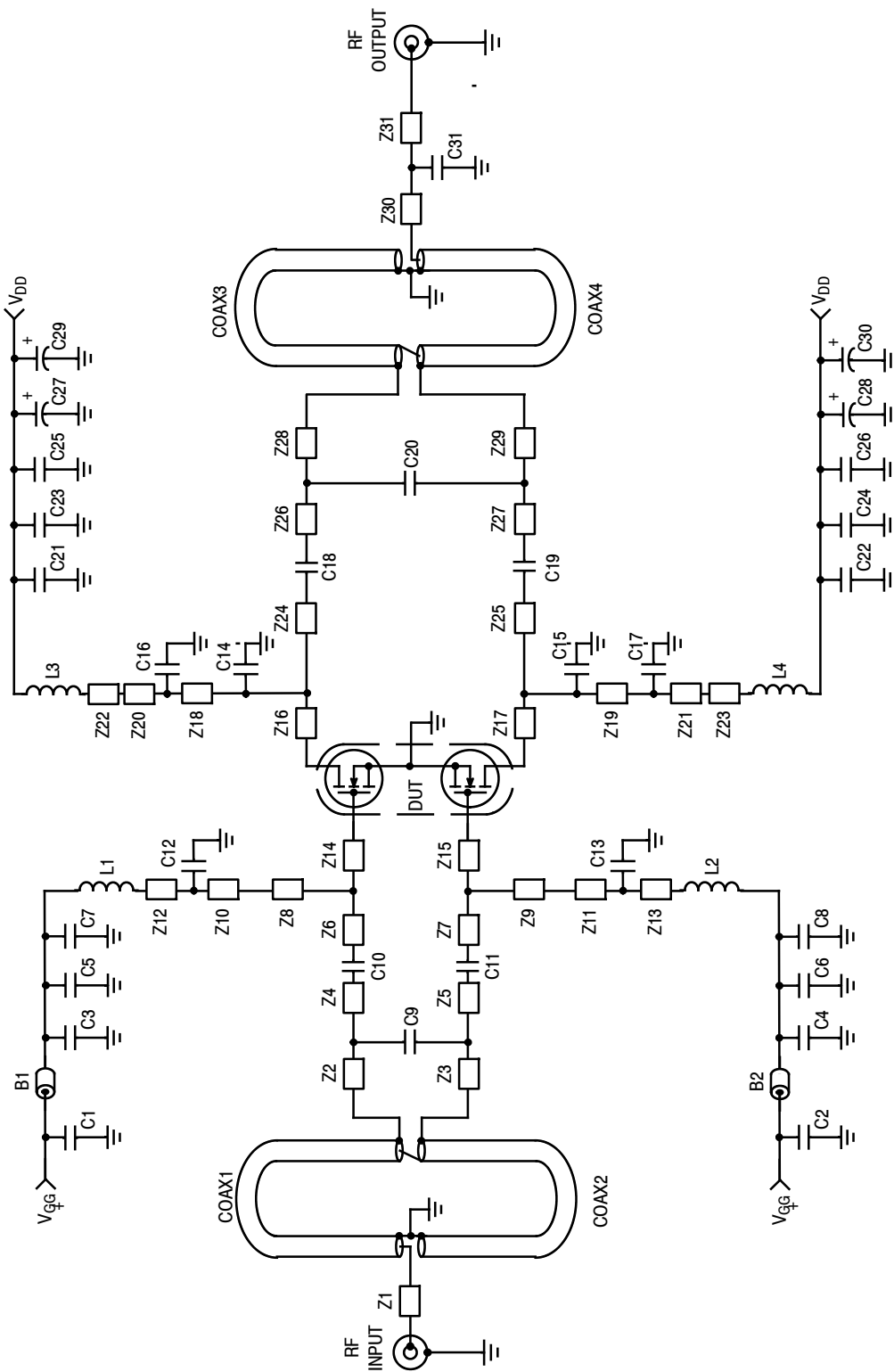


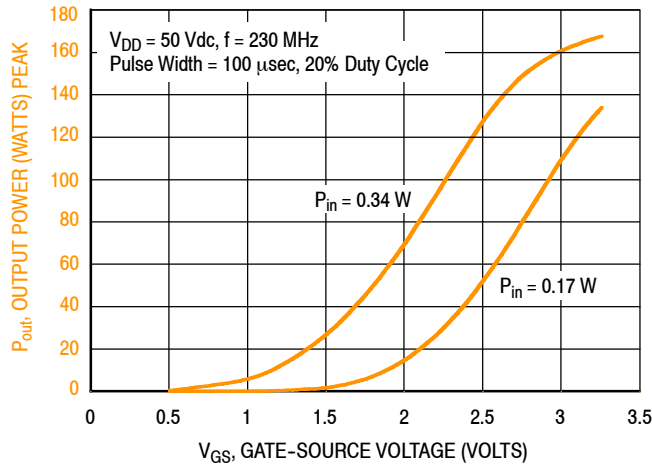
Figure 6. MMRF1320N Narrowband Test Circuit Schematic — 230 MHz

Table 8. MMRF1320N Narrowband Test Circuit Microstrips — 230 MHz

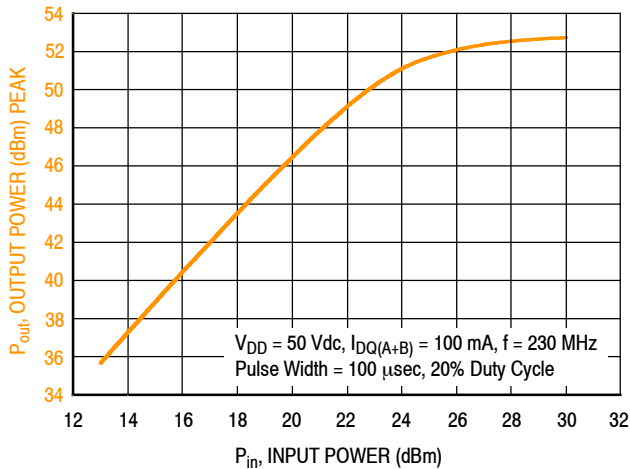
| Microstrip | Description                | Microstrip | Description                |
|------------|----------------------------|------------|----------------------------|
| Z1         | 0.366" x 0.082" Microstrip | Z24, Z25   | 1.090" x 0.230" Microstrip |
| Z2, Z3     | 0.690" x 0.120" Microstrip | Z26, Z27   | 0.093" x 0.230" Microstrip |
| Z4, Z5     | 0.134" x 0.120" Microstrip | Z28, Z29   | 0.144" x 0.230" Microstrip |
| Z6, Z7     | 0.395" x 0.120" Microstrip | Z30        | 0.262" x 0.082" Microstrip |
| Z8*, Z9*   | 0.125" x 0.058" Microstrip | Z31        | 0.102" x 0.082" Microstrip |
| Z10, Z11   | 0.450" x 0.058" Microstrip |            |                            |

\* Line length include microstrip bands

## TYPICAL CHARACTERISTICS — 230 MHz

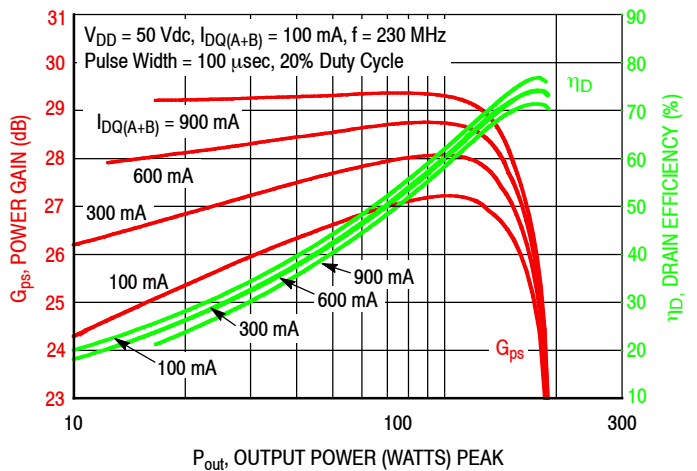


**Figure 7. Output Power versus Gate-Source Voltage at a Constant Input Power**

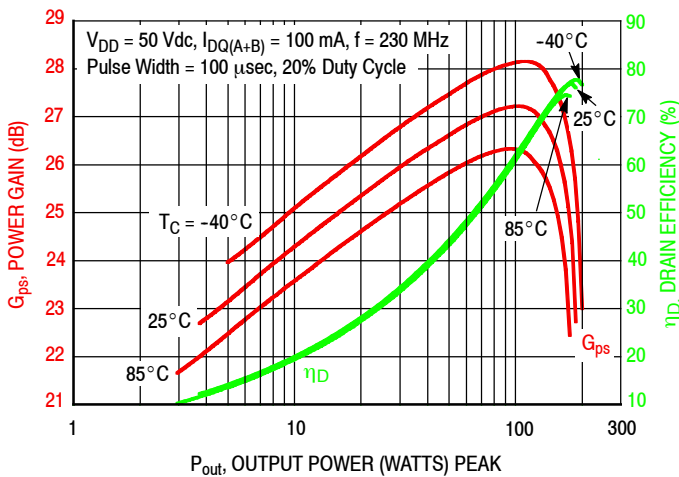


| f<br>(MHz) | P1dB<br>(W) | P3dB<br>(W) |
|------------|-------------|-------------|
| 230        | 159         | 182         |

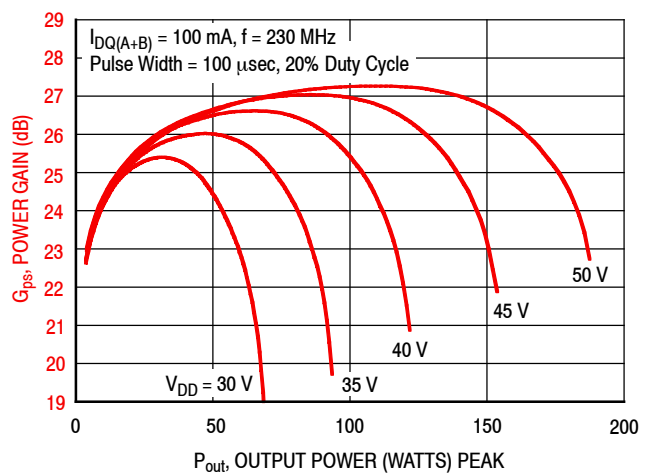
**Figure 8. Output Power versus Input Power**



**Figure 9. Power Gain and Drain Efficiency versus Output Power and Quiescent Current**



**Figure 10. Power Gain and Drain Efficiency versus Output Power**



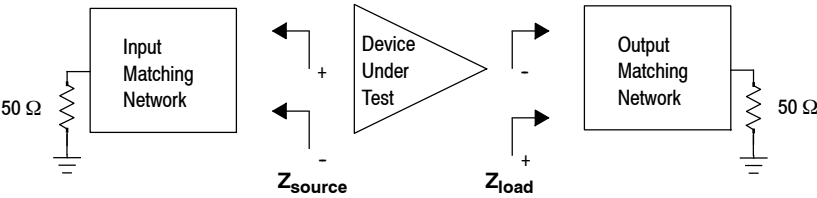
**Figure 11. Power Gain versus Output Power and Drain-Source Voltage**

# 230 MHz NARROWBAND PRODUCTION TEST FIXTURE

| f<br>MHz | $Z_{\text{source}}$<br>$\Omega$ | $Z_{\text{load}}$<br>$\Omega$ |
|----------|---------------------------------|-------------------------------|
| 230      | $6.2 + j17.7$                   | $12.1 + j12.5$                |

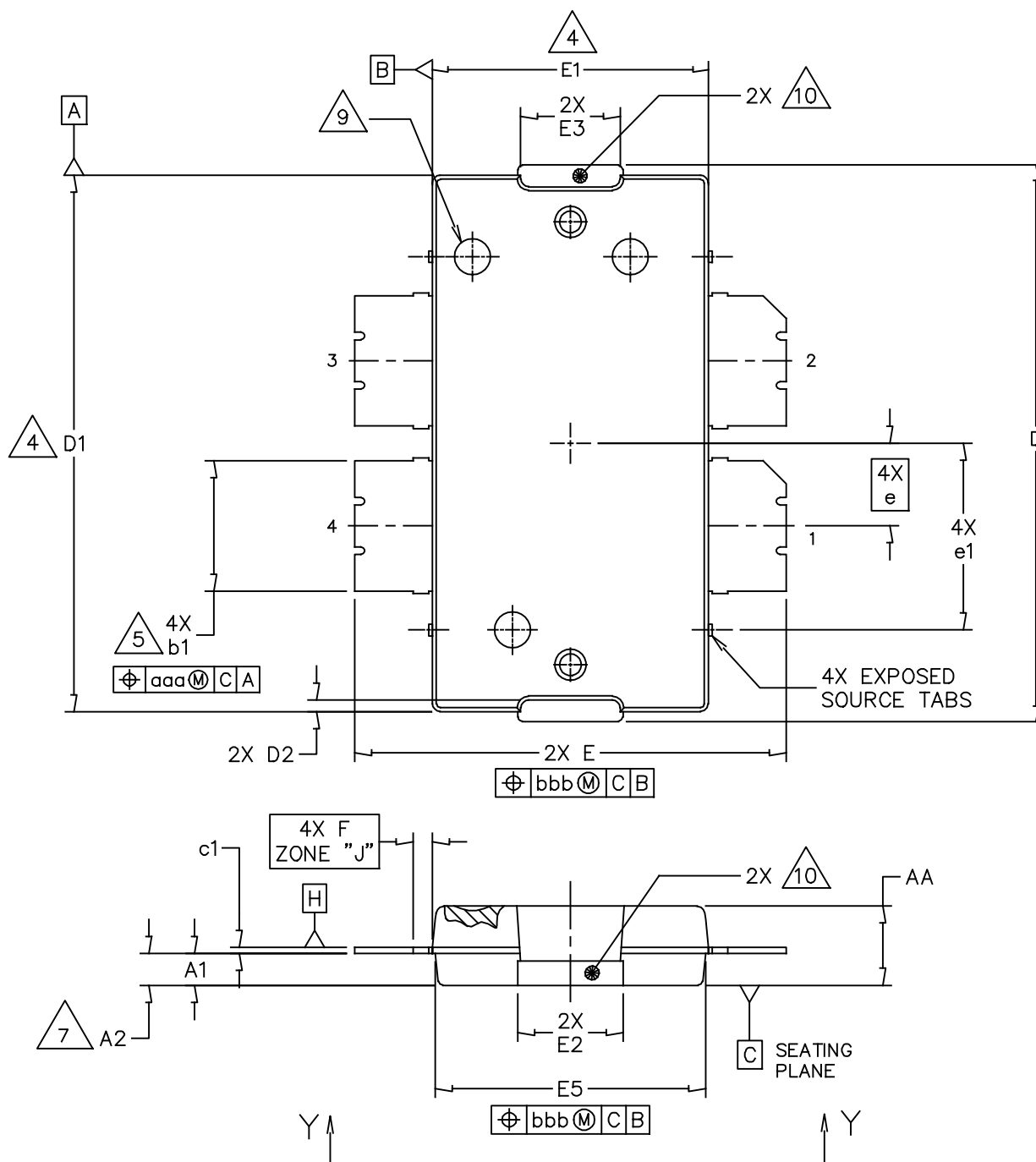
$Z_{\text{source}}$  = Test circuit impedance as measured from gate to gate, balanced configuration.

$Z_{\text{load}}$  = Test circuit impedance as measured from drain to drain, balanced configuration.

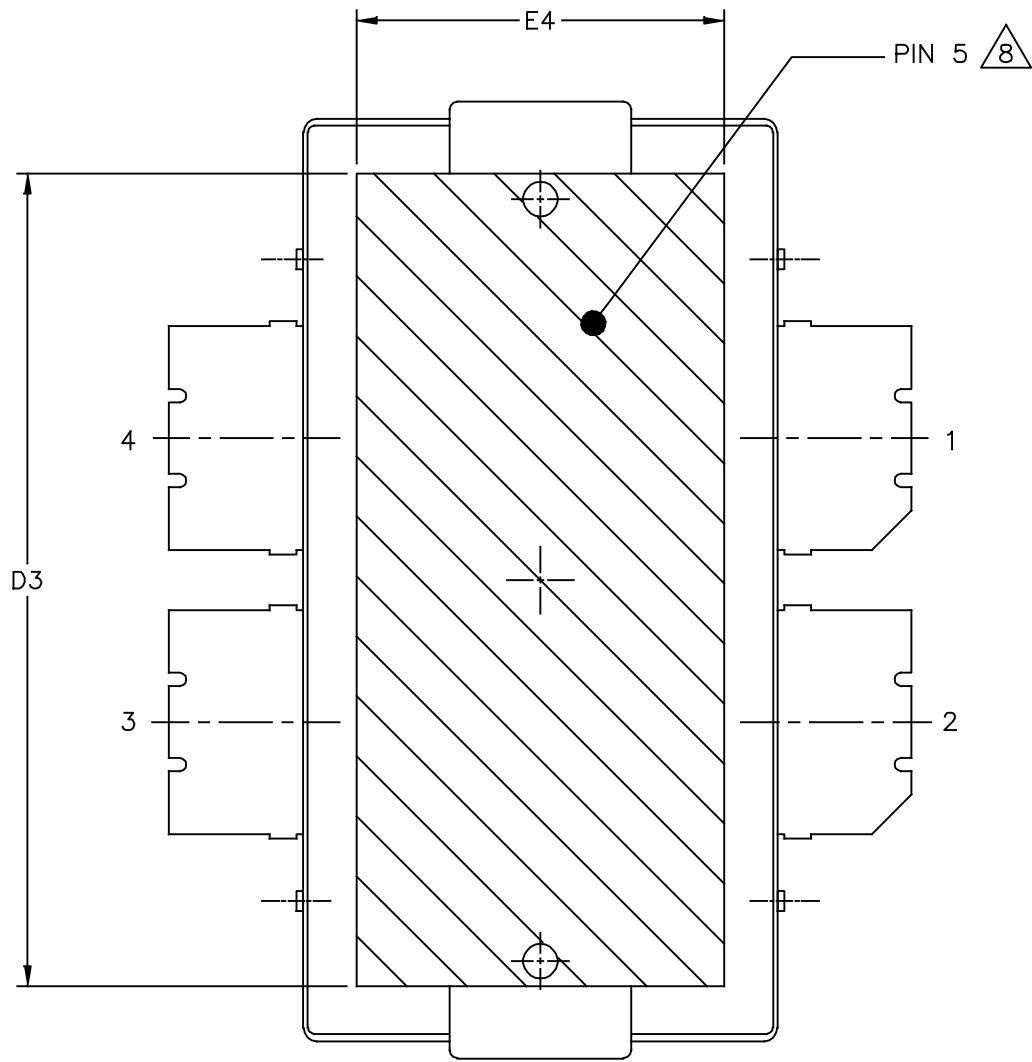


**Figure 12. Narrowband Series Equivalent Source and Load Impedance — 230 MHz**

## PACKAGE DIMENSIONS



|                                                         |  |                    |                          |                            |        |
|---------------------------------------------------------|--|--------------------|--------------------------|----------------------------|--------|
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED. |  | MECHANICAL OUTLINE |                          | PRINT VERSION NOT TO SCALE |        |
| TITLE:<br><br>TO-270WB-4                                |  |                    | DOCUMENT NO: 98ASA10577D |                            | REV: E |
|                                                         |  |                    | STANDARD: NON-JEDEC      |                            |        |
|                                                         |  |                    | 27 AUG 2013              |                            |        |



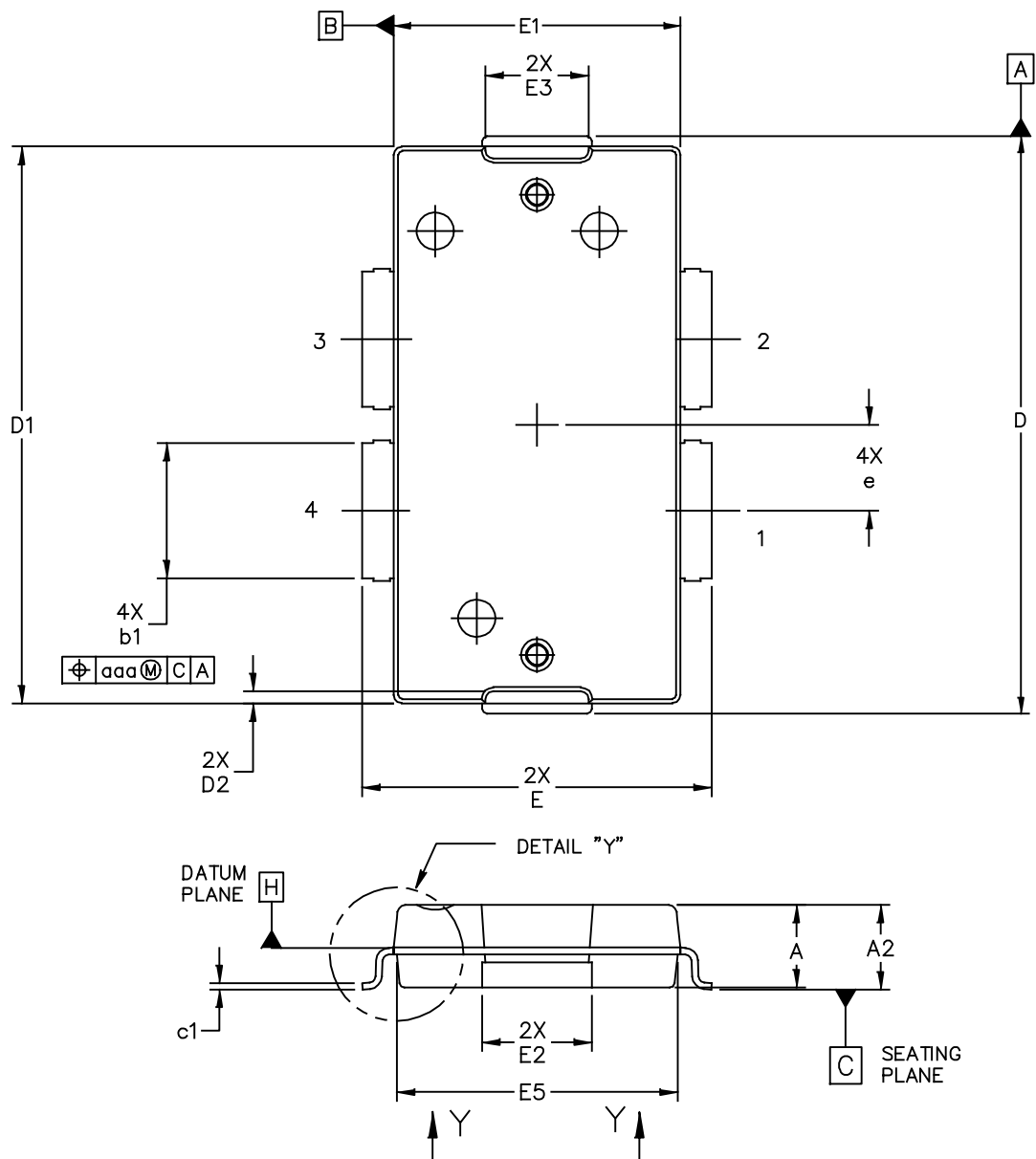
VIEW Y-Y

|                                                         |                                      |                            |
|---------------------------------------------------------|--------------------------------------|----------------------------|
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED. | MECHANICAL OUTLINE                   | PRINT VERSION NOT TO SCALE |
| TITLE:<br><br>TO-270WB-4                                | DOCUMENT NO: 98ASA10577D      REV: E |                            |
|                                                         | STANDARD: NON-JEDEC                  |                            |
|                                                         | 27 AUG 2013                          |                            |

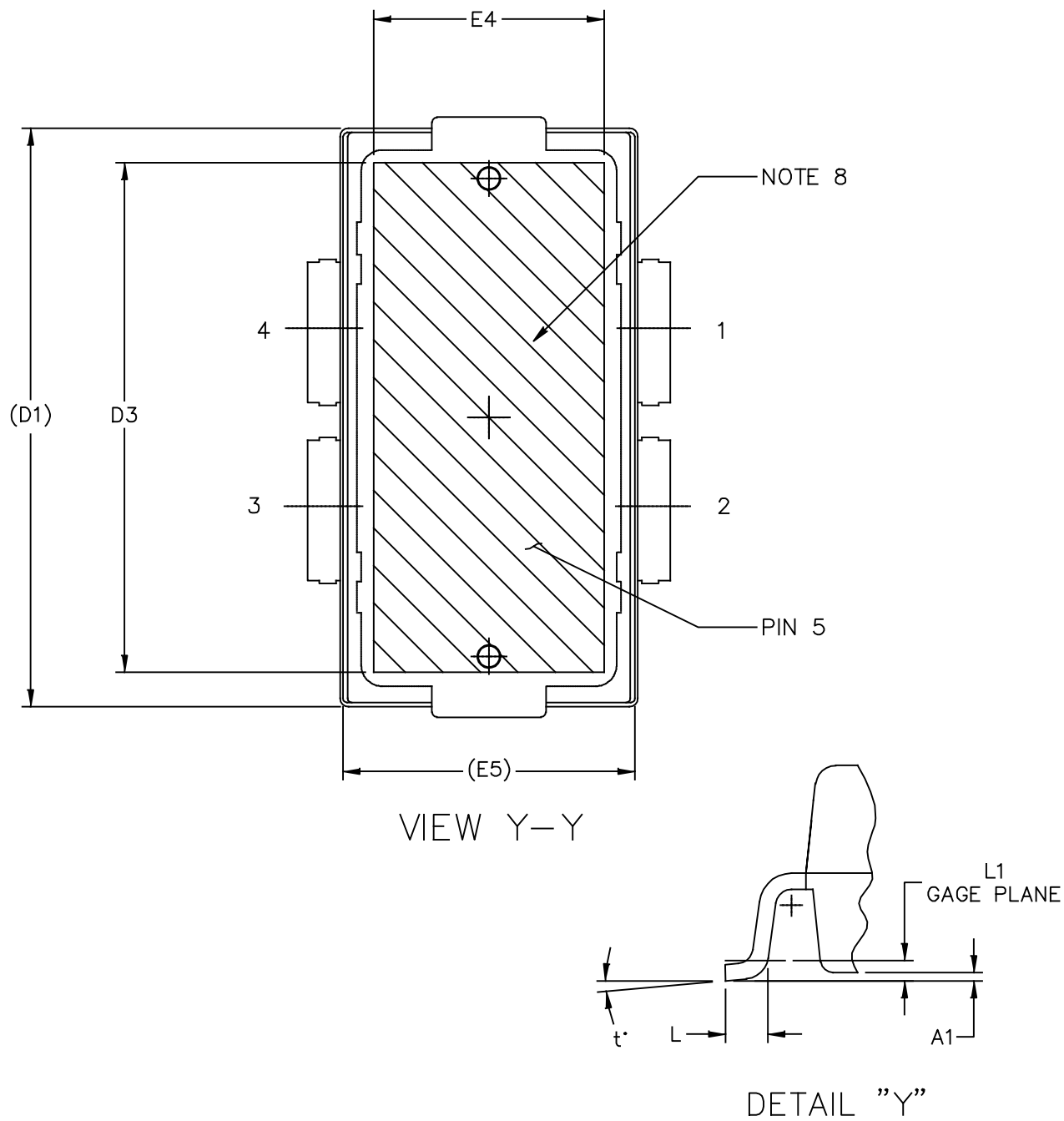
# NOTES:

1. CONTROLLING DIMENSION: INCH
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
3. DATUM PLANE H IS LOCATED AT THE TOP OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE TOP OF THE PARTING LINE.
4. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS .006 INCH (0.15MM) PER SIDE. DIMENSIONS D1 AND E1 DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE H.
5. DIMENSIONS b1 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .005 INCH (0.13MM) TOTAL IN EXCESS OF THE b1 DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. DATUMS A AND B TO BE DETERMINED AT DATUM PLANE H.
7. DIMENSION A2 APPLIES WITHIN ZONE J ONLY.
8. HATCHING REPRESENTS THE EXPOSED AREA OF THE HEAT SLUG. DIMENSIONS D3 AND D4 REPRESENT THE VALUES BETWEEN THE TWO OPPOSITE POINTS ALONG THE EDGES OF EXPOSED AREA OF HEAT SLUG.
9. DIMPLED HOLE REPRESENTS INPUT SIDE.
10. THESE SURFACES OF THE HEAT SLUG ARE NOT PART OF THE SOLDERABLE SURFACES AND MAY REMAIN UNPLATED.

| INCH                                                    |      |      | MILLIMETER         |       | DIM                                                  | INCH                       |      | MILLIMETER     |      |
|---------------------------------------------------------|------|------|--------------------|-------|------------------------------------------------------|----------------------------|------|----------------|------|
| DIM                                                     | MIN  | MAX  | MIN                | MAX   |                                                      | MIN                        | MAX  | MIN            | MAX  |
| AA                                                      | .100 | .104 | 2.54               | 2.64  | F                                                    | .025 BSC                   |      | 0.64 BSC       |      |
| A1                                                      | .039 | .043 | 0.99               | 1.09  | b1                                                   | .164                       | .170 | 4.17           | 4.32 |
| A2                                                      | .040 | .042 | 1.02               | 1.07  | c1                                                   | .007                       | .011 | 0.18           | 0.28 |
| D                                                       | .712 | .720 | 18.08              | 18.29 | e                                                    | .106 BSC                   |      | 2.69 BSC       |      |
| D1                                                      | .688 | .692 | 17.48              | 17.58 | e1                                                   | .239 INFO ONLY             |      | 6.07 INFO ONLY |      |
| D2                                                      | .011 | .019 | 0.28               | 0.48  | aaa                                                  | .004                       |      | 0.10           |      |
| D3                                                      | .600 | ---  | 15.24              | ---   | bbb                                                  | .008                       |      | 0.20           |      |
| E                                                       | .551 | .559 | 14.00              | 14.20 |                                                      |                            |      |                |      |
| E1                                                      | .353 | .357 | 8.97               | 9.07  |                                                      |                            |      |                |      |
| E2                                                      | .132 | .140 | 3.35               | 3.56  |                                                      |                            |      |                |      |
| E3                                                      | .124 | .132 | 3.15               | 3.35  |                                                      |                            |      |                |      |
| E4                                                      | .270 | ---  | 6.86               | ---   |                                                      |                            |      |                |      |
| E5                                                      | .346 | .350 | 8.79               | 8.89  |                                                      |                            |      |                |      |
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED. |      |      | MECHANICAL OUTLINE |       |                                                      | PRINT VERSION NOT TO SCALE |      |                |      |
| TITLE:<br><br>TO-270WB-4                                |      |      |                    |       | DOCUMENT NO: 98ASA10577D                      REV: E |                            |      |                |      |
|                                                         |      |      |                    |       | STANDARD: NON-JEDEC                                  |                            |      |                |      |
|                                                         |      |      |                    |       | 27 AUG 2013                                          |                            |      |                |      |



|                                                         |  |                           |                            |
|---------------------------------------------------------|--|---------------------------|----------------------------|
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED. |  | MECHANICAL OUTLINE        | PRINT VERSION NOT TO SCALE |
| TITLE: TO-270<br>4 LEAD, WIDE BODY<br>GULL WING         |  | DOCUMENT NO: 98ASA10578D  | REV: D                     |
|                                                         |  | CASE NUMBER: 1487-05      | 03 AUG 2007                |
|                                                         |  | STANDARD: JEDEC TO-270 BB |                            |



|                                                         |                    |                            |             |
|---------------------------------------------------------|--------------------|----------------------------|-------------|
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| TITLE: TO-270<br>4 LEAD, WIDE BODY<br>GULL WING         |                    | DOCUMENT NO: 98ASA10578D   | REV: D      |
|                                                         |                    | CASE NUMBER: 1487-05       | 03 AUG 2007 |
|                                                         |                    | STANDARD: JEDEC TO-270 BB  |             |

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5. DIMENSION "b1" DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .005 (0.13) TOTAL IN EXCESS OF THE "b1" DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. HATCHING REPRESENTS THE EXPOSED AREA OF THE HEAT SLUG.

## STYLE 1:

PIN 1 - DRAIN  
 PIN 2 - DRAIN  
 PIN 3 - GATE  
 PIN 4 - GATE  
 PIN 5 - SOURCE

| INCH                                                    |      |       | MILLIMETER |                    | INCH                      |          |                            | MILLIMETER |             |
|---------------------------------------------------------|------|-------|------------|--------------------|---------------------------|----------|----------------------------|------------|-------------|
| DIM                                                     | MIN  | MAX   | MIN        | MAX                | DIM                       | MIN      | MAX                        | MIN        | MAX         |
| A                                                       | .100 | .104  | 2.54       | 2.64               | L                         | .018     | .024                       | 0.46       | 0.61        |
| A1                                                      | .001 | .004  | 0.02       | 0.10               | L1                        | .01 BSC  |                            | 0.25 BSC   |             |
| A2                                                      | .101 | .108  | 2.56       | 2.74               | b1                        | .164     | .170                       | 4.17       | 4.32        |
| D                                                       | .712 | .720  | 18.08      | 18.29              | c1                        | .007     | .011                       | .18        | .28         |
| D1                                                      | .688 | .692  | 17.48      | 17.58              | e                         | .106 BSC |                            | 2.69 BSC   |             |
| D2                                                      | .011 | .019  | 0.28       | 0.48               | t                         | 2*       | 8*                         | 2*         | 8*          |
| D3                                                      | .600 | ----- | 15.24      | -----              | aaa                       | .004     |                            | 0.1        |             |
| E                                                       | .429 | .437  | 10.90      | 11.10              |                           |          |                            |            |             |
| E1                                                      | .353 | .357  | 8.97       | 9.07               |                           |          |                            |            |             |
| E2                                                      | .132 | .140  | 3.35       | 3.56               |                           |          |                            |            |             |
| E3                                                      | .124 | .132  | 3.15       | 3.35               |                           |          |                            |            |             |
| E4                                                      | .270 | ----- | 6.86       | -----              |                           |          |                            |            |             |
| E5                                                      | .346 | .350  | 8.79       | 8.89               |                           |          |                            |            |             |
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| TITLE: TO-270<br>4 LEAD, WIDE BODY<br>GULL WING         |      |       |            |                    | DOCUMENT NO: 98ASA10578D  |          |                            |            | REV: D      |
|                                                         |      |       |            |                    | CASE NUMBER: 1487-05      |          |                            |            | 03 AUG 2007 |
|                                                         |      |       |            |                    | STANDARD: JEDEC TO-270 BB |          |                            |            |             |

## PRODUCT DOCUMENTATION, SOFTWARE AND TOOLS

Refer to the following resources to aid your design process.

### Application Notes

- AN1955: Thermal Measurement Methodology of RF Power Amplifiers

### Engineering Bulletins

- EB212: Using Data Sheet Impedances for RF LDMOS Devices

### Software

- Electromigration MTTF Calculator

### To Download Resources Specific to a Given Part Number:

1. Go to <http://www.freescale.com/rf>
2. Search by part number
3. Click part number link
4. Choose the desired resource from the drop down menu

## REVISION HISTORY

The following table summarizes revisions to this document.

| Revision | Date      | Description                     |
|----------|-----------|---------------------------------|
| 0        | July 2015 | • Initial Release of Data Sheet |

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